XPT IGBT

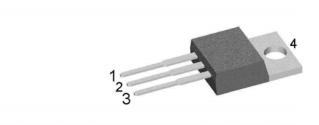
IXA20I1200PB

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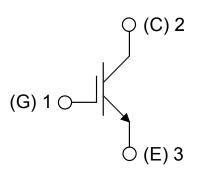
V_{ces}	=	1200 V
_{C25}	=	38A
$V_{\text{CE(sat)}}$	=	1.8V

Single IGBT

Part number IXA20I1200PB



Backside: collector



Features / Advantages:

- Easy paralleling due to the positive temperature coefficient of the on-state voltage
- Rugged XPT design (Xtreme light Punch Through) results in:
 - short circuit rated for 10 µsec.
 - very low gate charge
- low EMI
- square RBSOA @ 3x Ic
- Thin wafer technology combined with the XPT design results in a competitive low VCE(sat)

Applications:

- AC motor drives
- Solar inverter
- Medical equipment
- Uninterruptible power supply
- Air-conditioning systems
- Welding equipment
 Switched-mode and resonant-mode power supplies
- Inductive heating, cookers
- Pumps, Fans

Package: TO-220

- · Industry standard outline
- RoHS compliant • Epoxy meets UL 94V-0

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IGBT						Ratings	;	
Symbol	Definition		Conditions		min.	typ.	max.	Unit
V _{CES}	collector emitter voltage			$T_{VJ} = 25^{\circ}C$			1200	V
V _{GES}	max. DC gate voltage						±20	V
V _{GEM}	max. transient gate emitter voltage						±30	V
I _{C25}	collector current			$T_c = 25^{\circ}C$			38	A
I _{C 80}				$T_c = 80^{\circ}C$			22	A
Ptot	total power dissipation			$T_c = 25^{\circ}C$			165	W
V _{CE(sat)}	collector emitter saturation voltage		I _c = 15A; V _{GE} = 15 V	$T_{VJ} = 25^{\circ}C$		1.8	2.1	V
				T _{vJ} = 125°C		2.1		V
V _{GE(th)}	gate emitter threshold voltage		I_{c} = 0.6mA; V_{GE} = V_{CE}	$T_{VJ} = 25^{\circ}C$	5.4	5.9	6.5	V
ICES	collector emitter leakage current		$V_{CE} = V_{CES}; V_{GE} = 0 V$	$T_{vJ} = 25^{\circ}C$			0.1	mA
				T _{vJ} = 125°C		0.1		mA
I _{GES}	gate emitter leakage current		$V_{GE} = \pm 20 V$				500	nA
Q _{G(on)}	total gate charge		V_{CE} = 600 V; V_{GE} = 15 V; I_{C} =	15 A		47		nC
t _{d(on)}	turn-on delay time)				70		ns
t,	current rise time			T 10500		40		ns
t _{d(off)}	turn-off delay time	l	inductive load	T _{vJ} = 125°C		250		ns
t _f	current fall time	7	$V_{CE} = 600 \text{ V}; I_{C} = 15 \text{ A}$			100		ns
Eon	turn-on energy per pulse		V_{GE} = ±15 V; R_G = 56 Ω			1.65		mJ
E _{off}	turn-off energy per pulse	J				1.7		mJ
RBSOA	reverse bias safe operating area	٦	$V_{GE} = \pm 15 \text{ V}; \text{ R}_{G} = 56 \Omega$	T _{vJ} = 125°C				
I _{CM}		ſ	V _{CEmax} = 1200 V				45	A
SCSOA	short circuit safe operating area	٦	V _{CEmax} = 900 V					
t _{sc}	short circuit duration	}	$V_{CE} = 900 V; V_{GE} = \pm 15 V$	T _{vJ} = 125°C			10	μs
l _{sc}	short circuit current	J	R_{G} = 56 Ω ; non-repetitive			60		А
R _{thJC}	thermal resistance junction to case						0.76	K/W
R _{thCH}	thermal resistance case to heatsink					0.50		K/W

IXYS reserves the right to change limits, conditions and dimensions.

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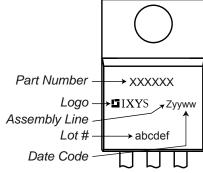


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Package TO-220			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I _{RMS}	RMS current	per terminal			35	Α
T _{vj}	virtual junction temperature		-40		150	°C
T _{op}	operation temperature		-40		125	°C
T _{stg}	storage temperature		-40		150	°C
Weight				2		g
M _D	mounting torque		0.4		0.6	Nm
F _c	mounting force with clip		20		60	Ν





Part number

- X = XPT IGBT A = Gen 1 / std
- 20 = Current Rating [A]
- I = Single IGBT
- 1200 = Reverse Voltage [V] PB = TO-220AB (3)

Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	IXA20I1200PB	IXA20I1200PB	Tube	50	507929

Similar Part	Package	Voltage class
IXA20IF1200HB	TO-247AD (3)	1200

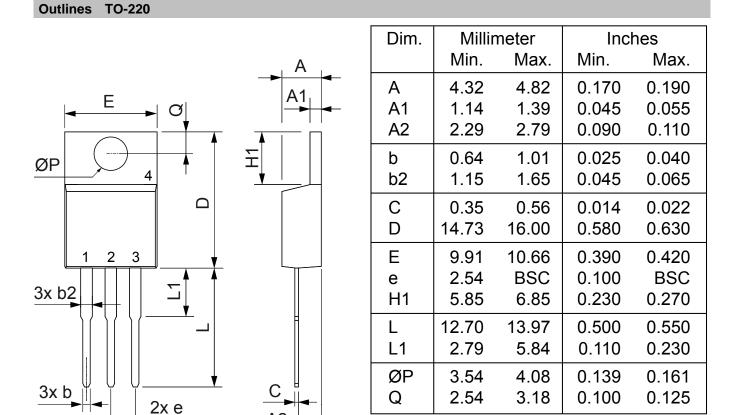
Equiva	lent Circuits for Simulation	* on die level	T _{vj} = 150 °C
	$-R_{o}$	IGBT	
V _{0 max}	threshold voltage	1.1	V
$R_{0 max}$	slope resistance *	86	mΩ

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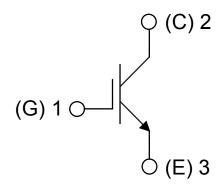
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